TMC6130 DATASHEET

Cost-effective high-current BLDC motor driver with state-of-the-art feature set. Fastest settling time and built-in EEPROM for extensive configuration.

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FFATURES AND BENEFITS

Level Shifting: µC PWM outputs / 6 or 3 ext. N-FET half-bridges

100% PWM Operation

Low Offset, Low Drift, Fast Current Sense Amplifier with configurable input range

Operating Range VM = [4.5, 28]V, 32V abs. max

Fault Interrupt & Feedback to microcontroller

Fastest settling time and minimum noise

Diagnostics: overcurrent, overtemperature, undervoltage

Configurable communication interface for diagnostics feedback

Drain-Source Voltage / Gate-Source Voltage external FET monitoring for short circuit protection

Sleep Mode with low quiescent current (<30µA)

Compatible with 3V and 5V microcontrollers

Charge-Pump provides NFET reverse polarity drive

Small Size: QFN 5x5mm package, 32 pins

Battery operated equipment

APPLICATIONS

Handcraft gear Professional healthcare Fail-safe applications Low-torque control applications BLDC sine wave applications Positioning Actuators Factory Automation Pumps and Valves CNC Machines

DESCRIPTION

The TMC6130 is a high-current motor driver for compact and energy efficient BLDC solutions. It is designed to drive N-type FET 3-phase motor control applications and contains all power and analog circuitry required for a high performance system. The built-in EEPROM allows extensive configurability without the need for external resistors and SPI interface programming. This reduces the pin count to only 32. All output voltages are monitored and controlled. The device comprises a current shunt amplifier with a high gain bandwidth (GBW), offering a fast settling time with low noise. A combination of bootstrap and charge pump enables driving 6 (or 3) NFETs, with gate charges up to 400nC/NFET with a minimum of device self-heating. Further, the IC reset level below 4.5V allows also for low-voltage operation.

BLOCK DIAGRAM

APPLICATION EXAMPLES: HIGH POWER – FASTEST SETTLING TIME

The TMC6130 3-phase motor pre-driver scores with a very fast settling time, high reliability, and broad diagnostic and safety features. It can be used within a large operating range from battery systems on up to 24V DC. This versatility covers a wide spectrum of applications and motor sizes, all while keeping costs down.

Several safe operating features are integrated, including diagnostics related to all output voltages, power on reset, and short circuit protection. Diagnostics feedback is communicated to the microcontroller via a bidirectional error interface. Finally, this BLDC driver chip features a low side shunt amplifier with large gain bandwidth (GBW), ideal for torque control applications requiring very fast settling time and minimum noise. Extensive support at the chip, board, and software levels enables rapid design cycles and fast time-to-market with competitive products.

Layout with MOSFET power module (B6-bridge)

TMC6130 EVALUATION BOARD

This evaluation board is a development platform for applications based on the TMC6130 three phase BLDC motor driver chip. Supply voltages are 4.5… 28V DC (max. 32V). The board features an embedded microcontroller with USB and RS232 (TTL level) interfaces for communication. The board offers test points for all pins of the TMC6130.

For positioning, three digital hall sensors can be connected as well as an ABN encoder. Using the IOs, potentiometers and switches can be attached.

TRINAMICs TMCM-BLDC software tool (running under Windows) enables access to all functions of the TMC6130 from a PC.

ORDER CODES

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1 Principles of Operation

Figure 1.1 Block diagram and principle operation circuit

1.1 Key Concepts

The TMC6130 BLDC motor pre-driver implements advanced features which contribute toward energy efficiency, high precision, high reliability, smooth motion, and cool operation in industrial BLDC motor applications.

TRINAMIC motor drivers also offer safeguards to detect/protect from shorted outputs, overtemperature, overvoltage, and undervoltage conditions.

1.2 Application Circuits

Figure 1.2 Application example for +12V DC

Figure 1.3 Application example for +24V DC

Figure 1.4 Ground connections

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GATE DRIVER CONNECTIONS

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DIGITAL IO CONNECTIONS

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2 Pin Assignments

2.1 Package Outline

Figure 2.1 TMC6130 pin assignments

2.2 Signal Descriptions

Table 2.1 Pin definitions and descriptions

3 Currents and Current Control

3.1 Supply Systems

The current for operation of the system is supplied via V_M and V_{CC} . V_{CC} supplies the IOs, and the amplifier. In case V_{CC} is supplied with a limited output impedance (for instance from a microcontroller IO), the performance of the amplifier may be affected. V_M supplies the internal operation and the charge pump.

There are two possibilities to connect the boost current capacitor to the TMC6130. For charge pump mode 0 (default setting), connect it to VCP as shown in Figure 3.1.

Figure 3.1 Power supply systems: CPMODE = 0 and CPMODE = 1

STANDARD OPERATION: CHARGE PUMP MODE = 0

The standard operation of the charge pump is to ensure sufficient gate voltage to the bootstrap capacitors in case of low voltage conditions. V_{BOOST} is regulated compared to GND level. The charge pump will not be switching when $V_M > V_{REG} + 2*V_F$ with V_F = forward voltage of charge pump diodes.

CHARGE PUMP MODE = 1 *(has to be programmed and stored in EEPROM via SPI)*

Alternatively, the charge pump can regulate V_{BOOST} compared to V_M . In this case the C_{BOOST} capacitor should be connected to V_M to ensure any supply variations are coupled to the V_{BOOST} level. The disadvantage is an additional amount of dissipation inside the pre-driver to regulate V_{REG} .

The default configuration is stored in the integrated EEPROM. In case CPMODE1 is desired, it is necessary to change EEPROM configuration bits (using the SPI interface or via bit banging).

3.2 100% PWM with Bootstrap

A current is drawn from the VCP_SW pin to the phase pins. This current will discharge the gate voltage on top of any external pull down gate resistance.

This gate leakage will limit the maximum state time during which 100% PWM can be applied.

3.3 Current Consumption in Sleep Mode

Sleep mode is activated when the supply input V_{CC} is pulled below $V_{CC\,SLEF}$ level. In sleep mode, the current consumption is reduced to IS_{SLEEP}.

ATTENTION!

In case input pins are externally pulled high while VCC is low, current will flow into VCC via internal protection diodes. *This condition is not allowed!* When VCC is pulled low, also ERROR will go low. This should not be interpreted as a diagnostic interrupt.

STATES IN SLEEP MODE

4 Diagnostics

4.1 ERROR Interface

ERROR is a serial interface that feeds back detailed diagnostics information to the microcontroller. Two modes for supplying diagnostic feedback can be used (configured in EEPROM). The default configuration for the TMC6130 is PWM_SPEED = 1.

In these modes detailed diagnostic information is provided in the form of a PWM duty cycle. Each error corresponds to one duty cycle. The duty cycle is transmitted until the microcontroller acknowledges the reception of the duty cycle. The microcontroller acknowledges by pulling the ERROR line low for a period t_{ACK} > tERROR.

¹ MCU pulls ERROR low.

Figure 4.1 ERROR handshake protocol

At each falling edge the TMC6130 checks the actual voltage on the ERROR line to detect an acknowledgement. When an acknowledgement is detected the duty cycle value is changed to the corresponding duty cycle value of the highest priority next error that has not yet been transmitted. This sequence of capturing duty cycle and acknowledging continues until the end of the frame (EOF) duty cycle has been received. By acknowledging the EOF duty cycle all error latches are reset and the ERROR line goes high again until a new error occurs.

ATTENTION

- It is possible that a lower priority error is transmitted before a higher priority error because the higher priority error occurred after the start of transmission of the lower priority error.
- When V_{CC} is pulled low to put the TMC6130 into sleep mode, ERROR will go low as well. As soon as V_{CC} goes high, ERROR will go high as well and remains high: no EOF is required in this case.
- As long as the regulated voltages on VCP and VCP_REG have not been achieved, ERROR may immediately start to go in diagnostic mode. This implies the microcontroller has to acknowledge these errors until the undervoltage conditions have been resolved. As soon as ERROR no longer enters diagnostic mode, the pre-driver is ready for operation.

² TMC6130 detects acknowledge on falling edge.

³ MCU releases ERROR line.

ACKNOWLEDGE ON ERROR

For the CPU to acknowledge ERROR it should be able to keep the line low while ERROR is pulling the line high.

Figure 4.2 ERROR output

OVERVIEW DIAGNOSTIC ERRORS

NOTES

- In case of multiple errors at the same time, priority is defined: 0 is highest priority, 16 is lowest priority.

- Duty cycle is transmitting with 5 bits resolution.
- Since the rise and fall times are matched, the resulting error is depending on the input comparator level of the microcontroller. If the comparator level is at VCC/2, there is no error. In any other case there is a systematic error which can be taken into account.

4.2 Hardware Protection

Hardware protection refers to the capability of the microcontroller to turn off the TMC6130 pre-driver without intervention in case of error condition. All gate voltages have to be pulled low to Z-state. An overvoltage condition on VM will always switch off the pre-driver, in order to protect it. This safety feature cannot be masked.

4.2.1 VDS Overvoltage

The reaction of the pre-driver on VDS (drain source voltage) overvoltage events can be configured in EEPROM with bridge feedback (BF) bits.

Per default configuration, *VDS_COMP_EN* and *VDS_BF_EN* are set to 1. Thus, in case of VDS overvoltage, ERROR reports error and the pre-driver becomes disabled.

For any other EEPROM configuration it is necessary to use the SPI interface or to communicate with the microcontroller via bit banging. Note, that in most cases it is not necessary to change EEPROM settings. Therefore, information about programming the EEPROM via SPI is subject of an application note and not mentioned here.

4.2.2 VCP_REG Overvoltage

The reaction of the pre-driver on VCP_REG overvoltage events can be configured in EEPROM with bridge feedback (BF) bits.

The default configuration is *VCP_REG_OV_BF_EN* = 1. Thus, ERROR reports error and bridge driver is set in tristate if the error flag *VCP_REG_OV* is set.

For any other EEPROM configuration it is necessary to use the SPI interface or to communicate with the microcontroller via bit banging. Note, that in most cases it is not necessary to change EEPROM settings. Therefore, information about programming the EEPROM via SPI is subject of an application note and not mentioned here.

4.2.3 Pre-driver Output State Summary

The table below shows all conditions due to which the pre-driver may be disabled.

5 EEPROM Default Configuration

A good pre-driver configuration is already done by TRINAMIC. The EEPROM features single error correction and double error detection.

EEPROM PROGRAMMING

The EEPROM data can be programmed by the microcontroller via an SPI interface. In most cases it is not necessary to change EEPROM settings. Therefore, information about programming the EEPROM via SPI is subject of an application note and not mentioned here.

MEMORY MAP

EEPROM BITS

5.1 Basic Information for SPI Communication

To communicate with the TMC6130 via SPI the motor has to be in standstill because of pin sharing. When the chip is in SPI mode the EEPROM is programmable and readable via the SPI port.

The TMC6130 switches from *normal mode* to *SPI mode* if the following conditions are met:

- $EN = 0$
- ERROR:
	- Any pending errors have been acknowledged
	- All BHx = high
	- All BLx = low
	- A Low Level pulse is applied on ERROR between 256us (2048 Tclk) and 512us (4096 Tclk))

The chip returns from SPI mode to normal mode when

 $EN = 1$.

This means that any ongoing EEPROM writes will be completed and the EEPROM state machine will copy all EEPROM contents into registers. Then the chip will return to normal mode. During this time the ERROR pin will be kept low.

When the TMC6130 comes out of power ON reset, after leaving SPI mode and returning to normal mode, the pre-driver will be blocked until the data have been copied to the registers. This assures that all chip parameters are set correctly.

It only makes sense for the CPU to call for SPI if all errors are clear and acknowledged.

6 Sense Amplifier

The sense amplifier offers very low input offset, and very fast settling times. The input range can be adjusted by applying a suitable voltage on the VREF pin, typically as a resistor divider on VCC. For the definition of VREF, the input offset, the current range, and the linear output range of the CURRENT pin should all be taken into account.

 $V_{\text{ISENSE}} = (V_{\text{IN}} + / -V_{\text{OFFSET}}) * IS_{\text{GAN}} + V_{\text{REF}}$ has to be in the range [V_{ISENSE_MIN}, V_{ISENSE_MAX}]

 $I_{MIN} = \left[\left(V_{ISENSE~MIN} - V_{REF}\right) / I S_{GAN} + V_{OFFSET}\right] / R_{SHUNT}$

 $I_{MAX} = \left[\left(V_{ISENSE_MAX} - V_{REF}\right) / I S_{GAN} - V_{OFFSET}\right] / R_{SHUNT}$

The table below shows the current input range for two resistive divider settings on V_{REF} .

- **1.** $V_{REF} = VCC/2$ for a symmetrical input range
- **2.** V_{REF} = VCC/18 for a maximum current level, whilst ensuring it is possible to measure the input offset before starting the motor (ISENSE_MIN > 0A).

For ease of calculation a max temperature offset drift of 1mV was added to the 5mV offset. From this follows that the maximum input offset is 6mV.

6.1 Sense Amplifier Current Ranges: Examples for 1MΩ Shunt

- (*) Applying a GAIN of 28.7 or higher with DIV 18 for 3.3V does not allow the measure the input offset

- (**) examples taking a 10% supply variation into account.

7 FET Driver Implementation

7.1 Normal Operation

The top side FET drivers are bootstrapped drivers. Each of the six external FET transistors which have to be connected can be controlled directly via six digital inputs.

The six external FET transistors (or three half bridges) can also be controlled using only three digital input signals. Therefore, proceed as follows:

- Connect the BH*x* to VCC.
- Control the 3 phases via the BL*x* inputs. In this mode of operation, the TMC6130 will automatically generate the programmed dead times.

The drain source voltage VDS as well as the gate voltage VGS are monitored to ensure fail safe operation. The FET gate outputs are all pulled low by pulling ENABLE low.

7.2 FET Driver during Sleep Mode

In sleep mode, a gate discharge resistance ($R_{SGD} \sim 1K\Omega$) is activated. This ensures that the FET gates remain fully in OFF state. It is the responsibility of the microcontroller to ensure all gate voltages are low, for instance by setting the ENABLE input low, prior to switching to sleep mode.

Figure 7.1 Fet driver during sleep mode: BM*x* **is kept low with HS***x* **through the internal body diode of the TMC6130.**

8 Absolute Maximum Ratings

The maximum ratings may not be exceeded under any circumstances. Operating the circuit at or near more than one maximum rating at a time for extended periods shall be avoided by application design. All voltages are referenced to ground (GND). Positive currents flow into the IC. The absolute maximum ratings given in the table below are limiting values that do not lead to a permanent damage of the device but exceeding any of these limits may do so. Long term exposure to limiting values may affect the reliability of the device. Reliable operation of the IC is only specified within the limits shown in the table.

NOTES

* 1) Only during load dump pulse.

* 2) Equivalent to discharging a 100pF capacitor through a 1.5kΩ resistor conform to MIL STD 883 method 3015.7

 $*$ ³⁾ For applications with t_J > 125C: the extended temperature range is only allowed for a limited period of time. The application mission profile has to be agreed by TRINAMIC. Some analogue parameters may drift out of limits, but chip function is guaranteed.

9 General Electrical Specifications

9.1 Operational Range (*unless otherwise specified***)**

¹⁾ The info V_{CC_UV_X} is used to disable the control of the external FETs.

The charge pump of the TMC6130 can be used with three modes of operation.

VREG Warnings / CPMODE=X

²⁾ The driver on resistance is <5Ω at 25°C. Maximum values correspond with 150°C.

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10 Package Mechanical Data

10.1 QFN32 Dimensional Drawings

Attention: Drawings not to scale.

Figure 10.1 Dimensional drawings

General tolerance of D and E is ±0.1mm. Bottom pin 1 identification may vary depending on supplier.

10.2 Package Code

11 Disclaimer

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12 ESD Sensitive Device

The TMC6130 is an ESD-sensitive CMOS device and sensitive to electrostatic discharge. Take special care to use adequate grounding of personnel and machines in manual handling. After soldering the devices to the board, ESD requirements are more relaxed. Failure to do so can result in defects or decreased reliability.

Note: In a modern SMD manufacturing process, ESD voltages well below 100V are standard. A major source for ESD is hot-plugging the motor during operation. As the power MOSFETs are discrete devices, the device in fact is very rugged concerning any ESD event on the motor outputs. All other connections are typically protected due to external circuitry on the PCB.

13 Table of Figures

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15 References

[TMC6130-EVAL] TMC6130-EVAL Manual

Please refer to our web page http://www.trinamic.com.